

Polar™ **Power MOSFET**

IXTA3N100P IXTP3N100P IXTH3N100P

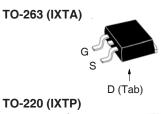
N-Channel Enhancement Mode Avalanche Rated

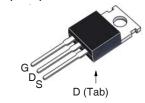


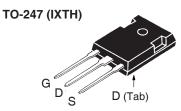
Symbol	Test Conditions	Maximum	Ratings
V _{DSS}	$T_{_{\rm J}} = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	1000	V
V _{DGR}	$T_{_{ m J}}$ = 25°C to 150°C, $R_{_{ m GS}}$ = 1M Ω	1000	V
V _{GSS} V _{GSM}	Continuous Transient	±20 ±30	V
I _{D25}	T _C = 25°C	3	Α
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	6	Α
IA	T _C = 25°C	3	Α
E _{AS}	$T_{c} = 25^{\circ}C$	200	mJ
dv/dt	$I_{_{S}} \le I_{_{DM}}, \ V_{_{DD}} \le V_{_{DSS}}, \ T_{_{J}} \le 150^{\circ}C$	10	V/ns
P _D	T _c = 25°C	125	W
T _J		-55 +150	°C
T_{JM}		150	°C
T _{stg}		-55 +150	°C
T _L T _{SOLD}	Maximum Lead Temperature for Solderi 1.6 mm (0.062in.) from Case for 10s	ng 300 260	°C °C
F _c	Mounting Force (TO-263) Mounting Torque (TO-220 & TO-247)	1065 / 2.214.6 1.13 / 10	N/lb Nm/lb.in
Weight	TO-263 TO-220 TO-247	2.5 3.0 6.0	g g

Symbol (T _J = 25°C,	Test Conditions Unless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
BV _{DSS}	$V_{GS} = 0V$, $I_D = 250\mu A$	1000			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	2.5		4.5	V
I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±50	nA
I _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$			5	μΑ
	$T_J = 125^{\circ}C$			250	μΑ
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$			4.8	Ω

1000V **3A** 4.8Ω R_{DS(on)}







G = Gate	D	= Drain
S = Source	Tab	= Drain

Features

- International Standard Packages
- Low $R_{DS(ON)}$ and Q_G Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls



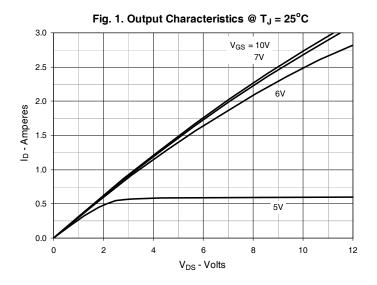
Symbol Test Conditions Char (T ₁ = 25°C, Unless Otherwise Specified) Min.		acteristic Values Typ. Max		
g _{fs}	$V_{DS} = 20V, I_{D} = 0.5 \bullet I_{D25}, Note 1$	1.5	2.4	S
\mathbf{C}_{iss}			1100	pF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		70	pF
C _{rss}			14.5	pF
t _{d(on)}	Resistive Switching Times		22	ns
t,	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		27	ns
t _{d(off)}	$R_{\rm G} = 18\Omega$ (External)		75	ns
t,	Ti _G = 1032 (External)		29	ns
$Q_{g(on)}$			36	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{D25}$		9	nC
\mathbf{Q}_{gd}			13	nC
R _{thJC}				1.0 °C/W
R _{thCS}	TO-220		0.50	°C/W
	TO-247		0.21	°C/W

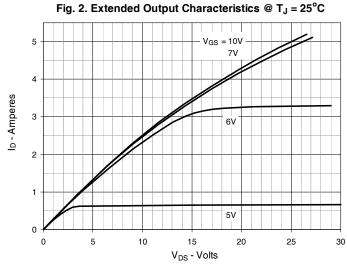
Source-Drain Diode

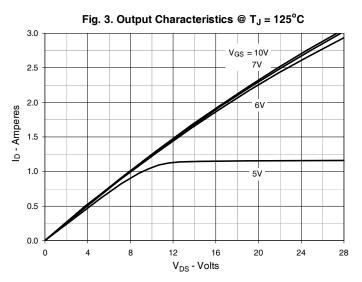
Symbol Test Conditions		Characteristic Values			
$(T_J = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max	
Is	$V_{GS} = 0V$			3	Α
SM	Repetitive, pulse Width Limited by ${\rm T}_{_{\rm JM}}$			9	Α
V _{SD}	$I_F = I_S$, $V_{GS} = 0V$, Note 1			1.5	V
t _{rr}	$I_F = 3A$, -di/dt = 100A/ μ s $V_R = 100V$		820		ns

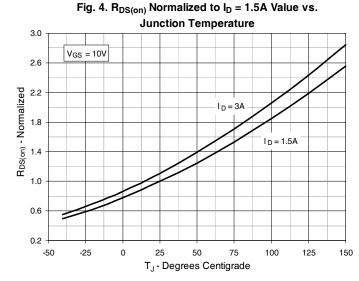
Note 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.

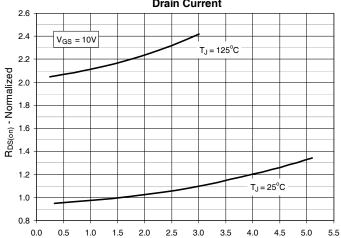












I_D - Amperes

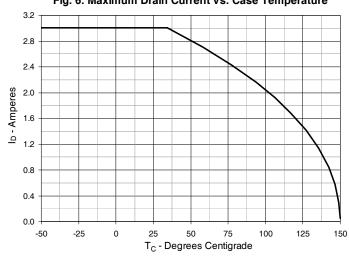
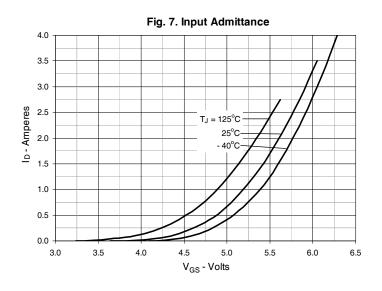


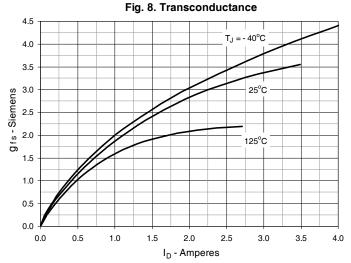
Fig. 5. $R_{DS(on)}$ Normalized to I_D = 1.5A Value vs.

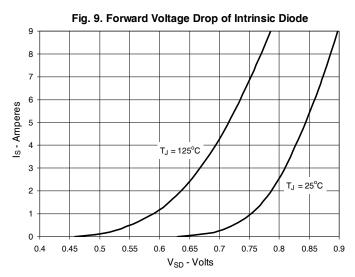
Drain Current

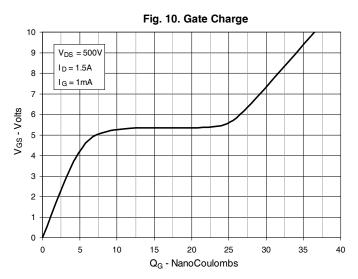
Fig. 6. Maximum Drain Current vs. Case Temperature

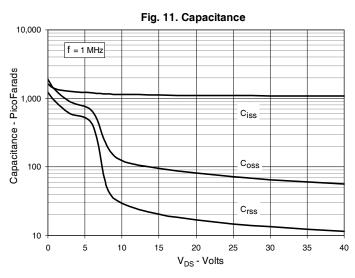


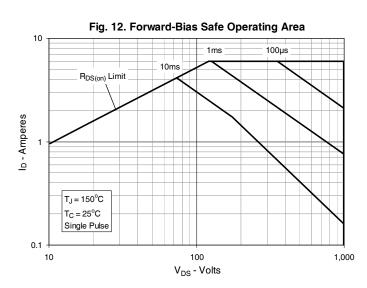












IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.



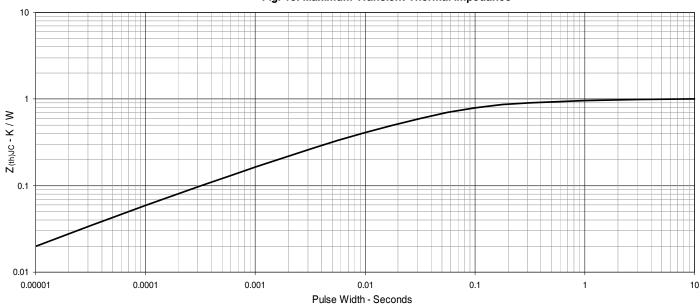
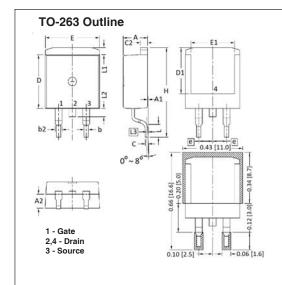
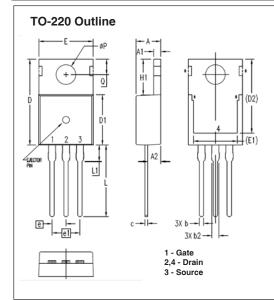


Fig. 13. Maximum Transient Thermal Impedance

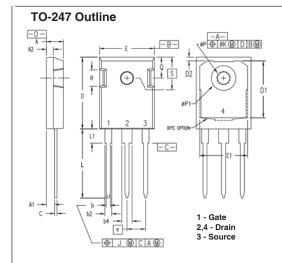




CVII	INCHES		MILLIMETER		
SYM	MIN	MAX	MIN	MAX	
Α	.170	.185	4.30	4.70	
A1	.000	.008	0.00	0.20	
A2	.091	.098	2.30	2.50	
b	.028	.035	0.70	0.90	
b2	.046	.060	1.18	1.52	
С	.018	.024	0.45	0.60	
C2	.049	.060	1.25	1.52	
D	.340	.370	8.63	9.40	
D1	.300	.327	7.62	8.30	
Ε	.380	.410	9.65	10.41	
E1	.270	.330	6.86	8.38	
е	.100	BSC	2.54 BSC		
Н	.580	.620	14.73	15.75	
L	.075	.105	1.91	2.67	
L1	.039	.060	1.00	1.52	
L2	_	.070	_	1.77	
L3	.010 BSC		0.254	BSC	



CVM	INCHES		MILLIMETERS	
SYM	MIN	MAX	MIN	MAX
Α	.169	.185	4.30	4.70
A1	.047	.055	1.20	1.40
A2	.079	.106	2.00	2.70
Ф	.024	.039	0.60	1.00
b2	.045	.057	1.15	1.45
0	.014	.026	0.35	0.65
D	.587	.626	14.90	15.90
D1	.335	.370	8.50	9.40
(D2)	.500	.531	12.70	13.50
E	.382	.406	9.70	10.30
(E1)	.283	.323	7.20	8.20
Φ	.100 BSC		2.54	BSC
e1	.200	BSC	5.08	BSC
H1	.244	.268	6.20	6.80
L	.492	.547	12.50	13.90
L1	.110	.154	2.80	3.90
ØΡ	.134	.150	3.40	3.80
Q	.106	.126	2.70	3.20



SYM	INCHES		MILLIMETERS	
STIVI	MIN	MAX	MIN	MAX
Α	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
Ь	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
С	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
Ε	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
е	.215	BSC	5.45	BSC
J		.010		0.25
K		.025		0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
ØΡ	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242	.242 BSC 6.15 BSC		BSC

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